

QM5HG-24

MEDIUM POWER SWITCHING USE
NON-INSULATED TYPE

QM5HG-24



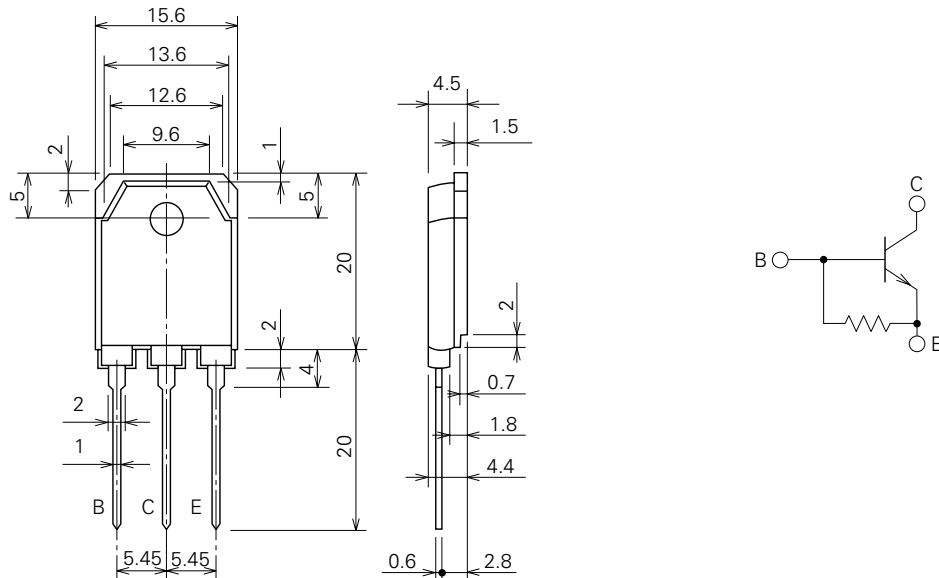
- **I_C** Collector current **5A**
- **V_{CEX}** Collector-emitter voltage **1200V**
- **h_{FE}** DC current gain **5**
- **Non-Insulated Type**

APPLICATION

Base driver for High voltage transistor modules

OUTLINE DRAWING & CIRCUIT DIAGRAM

Dimensions in mm



QM5HG-24

MEDIUM POWER SWITCHING USE
NON-INSULATED TYPE

ABSOLUTE MAXIMUM RATINGS (T_j=25°C, unless otherwise noted)

Symbol	Parameter	Conditions	Ratings	Unit
V _{CEX}	Collector-emitter voltage	V _{EB} =2V	1200	V
V _{CBO}	Collector-base voltage	Emitter open	1200	V
V _{EBO}	Emitter-base voltage	Collector open	7	V
I _C	Collector current	DC	5.0	A
P _C	Collector dissipation	T _C =25°C	100	W
I _B	Base current	DC	2	A
T _j	Junction temperature		-40~+150	°C
T _{stg}	Storage temperature		-40~+125	°C
—	Mounting torque	Mounting screw M3	0.59~0.98	N·m
—	Weight	Typical value	6~10	kg·cm
—	Weight	Typical value	5	g

ELECTRICAL CHARACTERISTICS (T_j=25°C, unless otherwise noted)

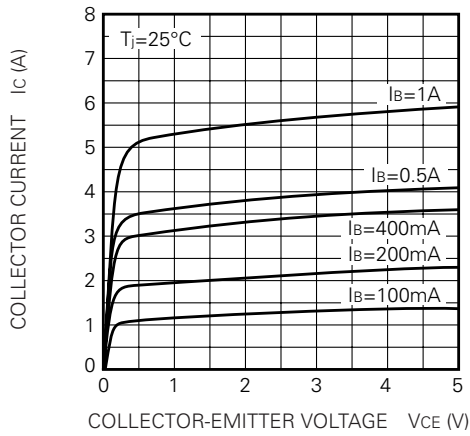
Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
I _{CX}	Collector cutoff current	V _{CE} =1200V, V _{EB} =2V	—	—	1.0	mA
I _{CBO}	Collector cutoff current	V _{CB} =1200V, Emitter open	—	—	1.0	mA
I _{EBO}	Emitter cutoff current	V _{EB} =7V	—	—	50	mA
V _{CE (sat)}	Collector-emitter saturation voltage	I _C =3A, I _B =0.6A	—	—	1.0	V
V _{BE (sat)}	Base-emitter saturation voltage	I _C =3A, I _B =0.6A	—	—	1.5	V
h _{FE}	DC current gain	I _C =3A, V _{CE} =1V	5	—	—	—
t _{on}	Switching time	V _{CC} =600V, I _C =3A, I _{B1} =0.6A, -I _{B2} =1.2A	—	—	1.0	μs
t _s			—	—	4.0	μs
t _f			—	—	0.8	μs
R _{th (j-c) Q}	Thermal resistance (junction to case)	Transistor part	—	—	1.25	°C/W
R _{th (j-c) R}		Diode part	—	—	—	°C/W
R _{th (c-f)}	Contact thermal resistance (case to fin)	Conductive grease applied	—	—	0.5	°C/W

QM5HG-24

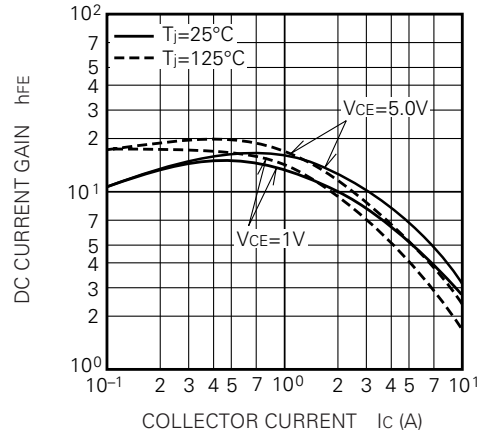
MEDIUM POWER SWITCHING USE
NON-INSULATED TYPE

PERFORMANCE CURVES

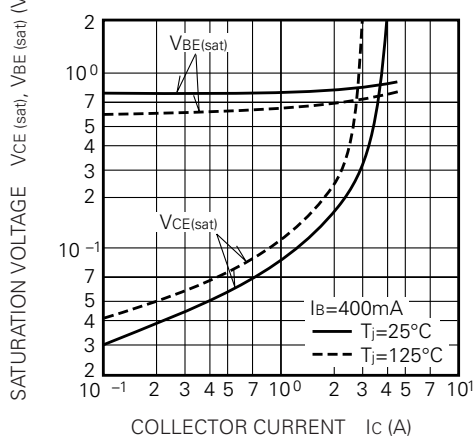
COMMON EMITTER OUTPUT
CHARACTERISTICS (TYPICAL)



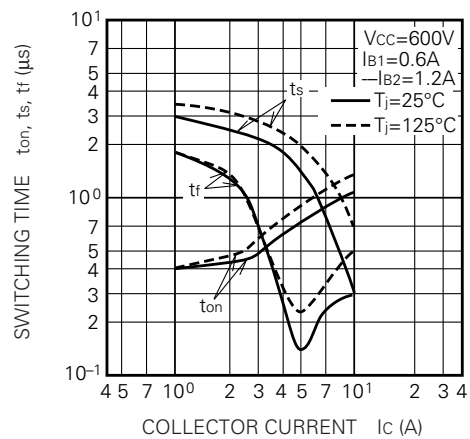
DC CURRENT GAIN VS.
COLLECTOR CURRENT (TYPICAL)



SATURATION VOLTAGE
CHARACTERISTICS (TYPICAL)



SWITCHING TIME VS. COLLECTOR
CURRENT (TYPICAL)



This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.